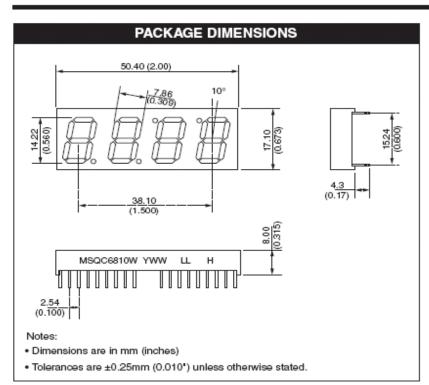


MSQC6810W



Features

- Bright Bold Segments
- Common Anode
- Low Power Consumption
- Low Current Capability
- Neutral Segments
- Grey Face
- Epoxy Encapsulated PCB
- High Performance
- High Reliability

Applications

- Appliances
- Automotive
- Instrumentation
- Process Control



MSQC6810W

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾ (T _A = 25°C, unless otherwise specified)				
Part Number Parameter	MSQC6810W	Units		
Continuous Forward Current (each segment)	20	mA		
Peak Forward Current (F = 10KHz, D/F = 1/10)	80	mA		
Power Dissipation (P _D)*	70	mW		
*Derate Linearly from 25°C	0.25	mW		
Reverse Voltage per Die	5 Volts	5 Volts		
Operating and Storage Temperature Range	-40°C to +85°C	-40°C to +85°C		
Lead soldering time (1/16 inch from standoffs)	5 seconds @ 230°	5 seconds @ 230°C		

ELECTRO-OPTICAL CHARACTERISTICS ⁽¹⁾ ($T_A = 25^{\circ}C$, unless otherwise specified)				
Part Number Parameter	MSQC6810W	Units	Test Condition	
Luminous intensity ⁽²⁾ (I _V)				
Cat G	1310 - 2358	μod	I _F = 10mA	
Cat H	2100 - 3780	μod	I _F = 10mA	
Forward Voltage (V _F)				
Typical (Standard Current)	2.10	v	I _F = 20mA	
Maximum (Standard Current)	2.80	v	I _F = 20mA	
Peak Wavelength Typ	589	nm	I _F = 10mA	
Dominant Wavelength	586 - 594	nm	I _F = 10mA	
Reverse Breakdown Voltage (V _R)	5	v	I _R = 100μΑ	
Spectral Line 1/2 Width	40	nm	I _F = 10mA	

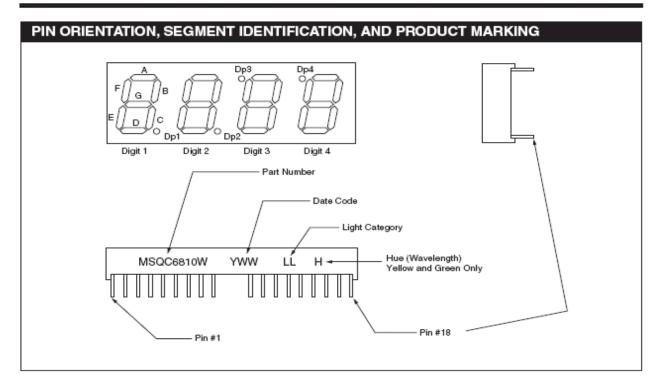
NOTES:

(1) Data per individual LED element

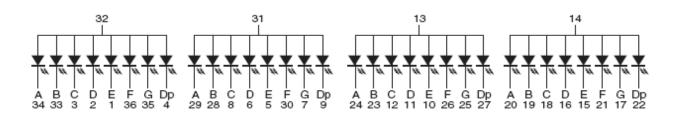
(2) Luminous intensity (µcd) = average light output per segment



MSQC6810W

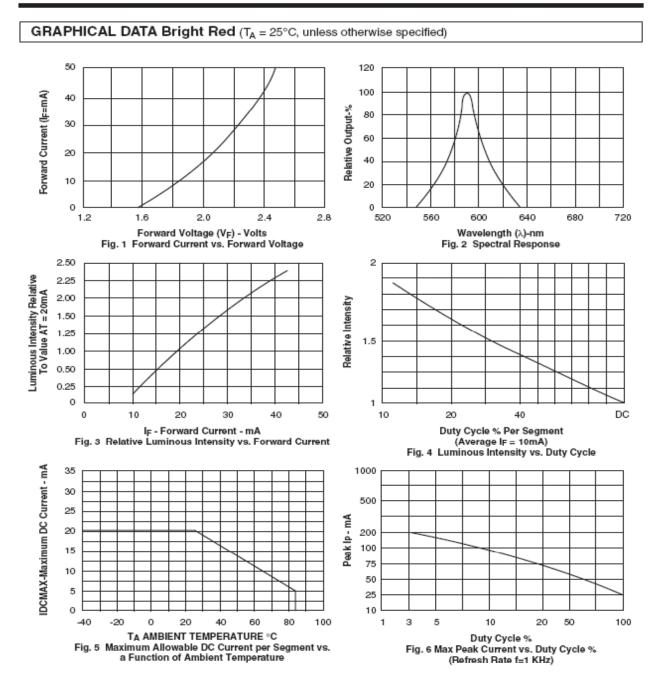


SCHEMATIC





MSQC6810W





MSQC6810W

Pin #	Connection
1	Cathode E for digit 1
2	Cathode D for digit 1
3	Cathode C for digit 1
4	Cathode DP for digit 1
5	Cathode E for digit 2
6	Cathode D for digit 2
7	Cathode G for digit 2
8	Cathode C for digit 2
9	Cathode DP for digit 2
10	Cathode E for digit 3
11	Cathode D for digit 3
12	Cathode C for digit 3
13	Common Anode for digit 3
14	Common Anode for digit 4
15	Cathode E for digit 4
16	Cathode D for digit 4
17	Cathode G for digit 4
18	Cathode C for digit 4
19	Cathode B for digit 4
20	Cathode A for digit 4
21	Cathode F for digit 4
22	Cathode DP for digit 4
23	Cathode B for digit 3
24	Cathode A for digit 3
25	Cathode G for digit 3
26	Cathode F for digit 3
27	Cathode DP for digit 3
28	Cathode B for digit 2
29	Cathode A for digit 2
30	Cathode F for digit 2
31	Common Anode for digit 2
32	Common Anode for digit 1
33	Cathode B for digit 1
34	Cathode A for digit 1
35	Cathode G for digit 1
36	Cathode F for digit 1



MSQC6810W

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